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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# **BOURNS®**

- Designed for Complementary Use with the TIP30 Series
- 30 W at 25°C Case Temperature
- 1 A Continuous Collector Current
- 3 A Peak Collector Current
- Customer-Specified Selections Available

TO-220 PACKAGE (TOP VIEW)

Pin 2 is in electrical contact with the mounting base.

MDTRACA

# This series is obsolete and not recommended for new designs.

## absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
	TIP29		80		
Collector-base voltage (I <sub>E</sub> = 0)	TIP29A		100	V	
	TIP29B	V <sub>СВО</sub>	120		
	TIP29C		140	 	
	TIP29		40		
Collector-emitter voltage (I <sub>B</sub> = 0)	TIP29A	V	60	V	
	TIP29B	V <sub>CEO</sub>	80		
	TIP29C		100		
Emitter-base voltage		V <sub>EBO</sub>	5	V	
Continuous collector current		I <sub>C</sub>	1	Α	
Peak collector current (see Note 1)		I <sub>CM</sub>	3	Α	
Continuous base current		I <sub>B</sub>	0.4	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		P <sub>tot</sub>	30	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note	3)	P <sub>tot</sub>	2	W	
Unclamped inductive load energy (see Note 4)		½Ll <sub>C</sub> <sup>2</sup>	32	mJ	
Operating junction temperature range		T <sub>j</sub>	-65 to +150	°C	
Storage temperature range		T <sub>stg</sub>	-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds		T <sub>L</sub>	250	°C	

NOTES: 1. This value applies for  $t_p \le 0.3$  ms, duty cycle  $\le 10\%$ .

- 2. Derate linearly to 150°C case temperature at the rate of 0.24 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = 0.4 A,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_S$  = 0.1  $\Omega$ ,  $V_{CC}$  = 20 V.



### electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA (see Note 5)	I <sub>B</sub> = 0	TIP29 TIP29A TIP29B TIP29C	40 60 80 100			V
I <sub>CES</sub>	Collector-emitter cut-off current	$V_{CE} = 80 \text{ V}$ $V_{CE} = 100 \text{ V}$ $V_{CE} = 120 \text{ V}$ $V_{CE} = 140 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	TIP29 TIP29A TIP29B TIP29C			0.2 0.2 0.2 0.2	mA
I <sub>CEO</sub>	Collector cut-off current	V <sub>CE</sub> = 30 V V <sub>CE</sub> = 60 V	$I_{B} = 0$ $I_{B} = 0$	TIP29/29A TIP29B/29C			0.3 0.3	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0				1	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_{\rm C} = 0.2  {\rm A}$ $I_{\rm C} = 1  {\rm A}$	(see Notes 5 and 6)	40 15		75	
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>B</sub> = 125 mA	I <sub>C</sub> = 1 A	(see Notes 5 and 6)			0.7	V
$V_{BE}$	Base-emitter voltage	V <sub>CE</sub> = 4 V	I <sub>C</sub> = 1 A	(see Notes 5 and 6)			1.3	V
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.2 A	f = 1 kHz	20			
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.2 A	f = 1 MHz	3			

NOTES: 5. These parameters must be measured using pulse techniques,  $t_0 = 300 \,\mu\text{s}$ , duty cycle  $\leq 2\%$ .

### thermal characteristics

	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			4.17	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

### resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t <sub>on</sub>	Turn-on time	I <sub>C</sub> = 1 A	I <sub>B(on)</sub> = 0.1 A	$I_{B(off)} = -0.1 \text{ A}$		0.5		μs
t <sub>off</sub>	Turn-off time	$V_{BE(off)} = -4.3 \text{ V}$	$R_L = 30 \Omega$	$t_p = 20 \ \mu s, \ dc \le 2\%$		2		μs

<sup>&</sup>lt;sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

<sup>6.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

h<sub>FE</sub> - DC Current Gain

0.001

### **TYPICAL CHARACTERISTICS**

# TYPICAL DC CURRENT GAIN VS COLLECTOR CURRENT $T_{CS631AD}$ $T_{C} = 4 \text{ V}$ $T_{C} = 25^{\circ}\text{C}$ $T_{D} = 300 \text{ µs, duty cycle} < 2\%$

I<sub>c</sub> - Collector Current - A Figure 1.

0.1

0.01

### COLLECTOR-EMITTER SATURATION VOLTAGE

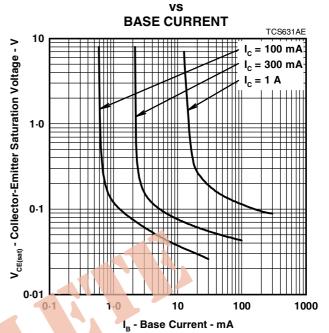
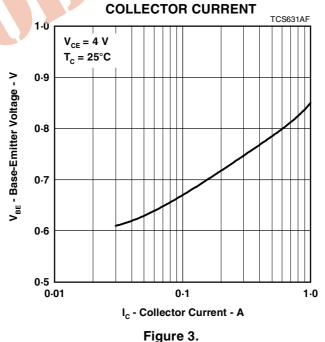


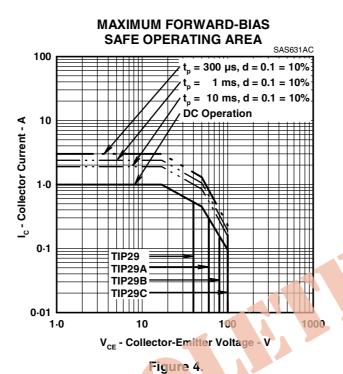
Figure 2.



1.0



### **MAXIMUM SAFE OPERATING REGIONS**



### THERMAL INFORMATION

### MAXIMUM POWER DISSIPATION

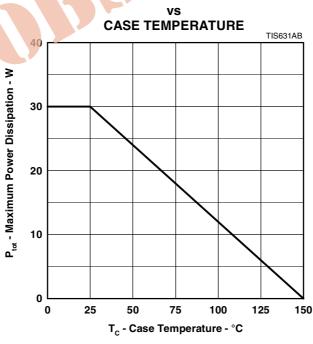


Figure 5.

### PRODUCT INFORMATION